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March 2014

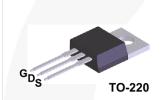
# FCP11N60/FCPF11N60

## **General Description**

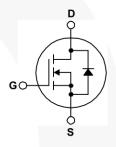
SuperFET® MOSFET is Fairchild Semiconductor's first genera-tion of high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switch-ing performance, dv/dt rate and higher avalanche energy. Con-sequently, SuperFET MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications.

#### **Features**

- 650V @T<sub>i</sub> = 150°C
- Typ. Rds(on)=0.32Ω
- Ultra low gate charge (typ. Qg=40nC)
- Low effective output capacitance (typ. Coss.eff=95pF)
- · 100% avalanche tested
- RoHS Compliant







## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter		FCP11N60 FCPF11N60		Units	
Drain Current - Continuous (T <sub>C</sub> = 2			11	11*	Α	
	- Continuous (T <sub>C</sub> = 100°C)		7	7*	Α	
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	33	33*	Α	
$V_{GSS}$	Gate-Source Voltage		±30		V	
E <sub>AS</sub>	Single Pulsed Avalanche Energy	(Note 2)	340		mJ	
I <sub>AR</sub>	Avalanche Current	(Note 1)	11		Α	
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	12.5		mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5		V/ns	
P <sub>D</sub>	Power Dissipation (T <sub>C</sub> = 25°C)		125	36	W	
	- Derate above 25°C		1.0	0.29	W/°C	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150		°C	
TL	Maximum lead temperature for soldering purposes,		300		°C	
'L	1/8" from case for 5 seconds		3	00		

# Thermal Characteristics

Symbol	Parameter	FCP11N60	FCPF11N60	Units
R <sub>OJC</sub>	Thermal Resistance, Junction-to-Case	1.0	3.5	°C/W
R <sub>ecs</sub>	Thermal Resistance, Case-to-Sink	0.5		°C/W
R <sub>0JA</sub>	R <sub>BJA</sub> Thermal Resistance, Junction-to-Ambient		62.5	°C/W

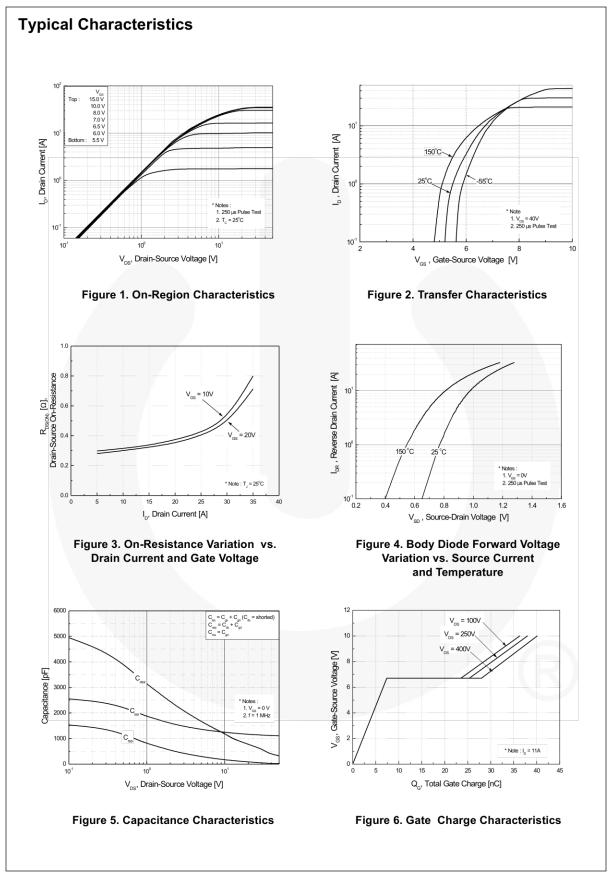
# **Package Marking and Ordering Information**

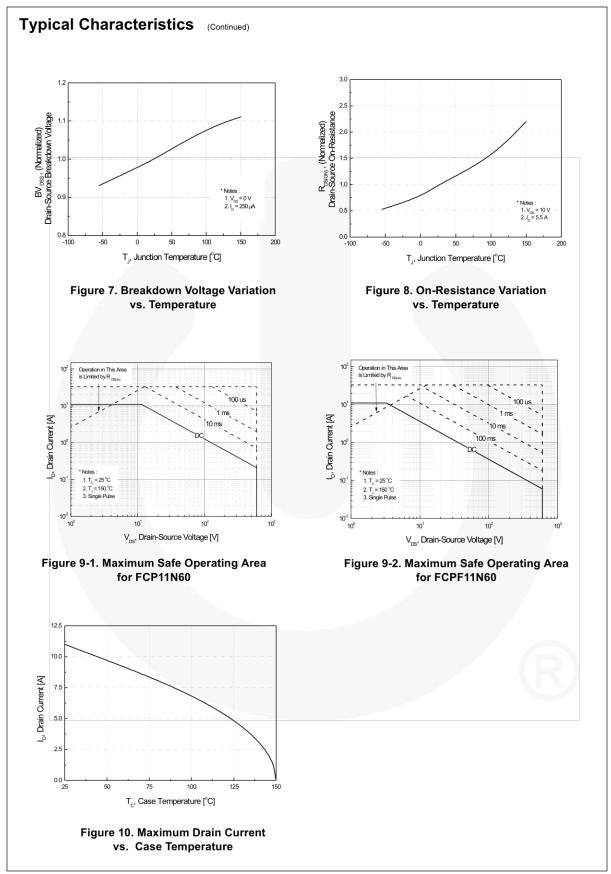
Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCP11N60	FCP11N60	TO-220	Tube	N/A	N/A	50 units
FCPF11N60	FCPF11N60	TO-220F	Tube	N/A	N/A	50 units
FCPF11N60T	FCPF11N60T	TO-220F	Tube	N/A	N/A	50 units

# **Electrical Characteristics** T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	aracteristics					
		$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}, T_J = 25^{\circ}\text{C}$	600			V
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}, T_J = 150^{\circ}\text{C}$		650		V
ΔBV <sub>DSS</sub> / ΔΤ <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250 μA, Referenced to 25°C		0.6		V/°C
BV <sub>DS</sub>	Drain-Source Avalanche Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 11 A		700		V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V			1	μΑ
		V <sub>DS</sub> = 480 V, T <sub>C</sub> = 125°C			10	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	V <sub>GS</sub> = -30 V, V <sub>DS</sub> = 0 V			-100	nA
On Cha	racteristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	3.0		5.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5.5 A		0.32	0.38	Ω
g <sub>FS</sub>	Forward Transconductance	$V_{DS} = 40 \text{ V}, I_{D} = 5.5 \text{ A}$ (Note 4)		9.7		S
Dynam	io Characteristics			ı	1	
-	ic Characteristics			1110	1400	»F
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1.0 \text{ MHz}$ $V_{DS} = 480 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1.0 \text{ MHz}$		1148 671	1490 870	pF
C <sub>rss</sub>	Output Capacitance					pF
Orss	Reverse Transfer Capacitance			63	82	pF
C <sub>oss</sub>	Output Capacitance			35		pF
C <sub>oss</sub> eff.	Effective Output Capacitance	V <sub>DS</sub> = 0V to 480 V, V <sub>GS</sub> = 0 V		95		pF
Switchi	ing Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			34	80	ns
t <sub>r</sub>	Turn-On Rise Time	V <sub>DD</sub> = 300 V, I <sub>D</sub> = 11 A,		98	205	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$R_G = 25 \Omega$		119	250	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4, 5)		56	120	ns
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> = 480 V, I <sub>D</sub> = 11 A,		40	52	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 480 \text{ V}, I_D = 11 \text{ A},$ $V_{GS} = 10 \text{ V}$		7.2		nC
Q <sub>gd</sub>	Gate-Drain Charge	VGS - 10 V (Note 4, 5)		21		nC
				l		
	Source Diode Characteristics an					
l <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				11	A
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current				33	A
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 11 A			1.4	V
t <sub>rr</sub>	Reverse Recovery Time	$V_{GS} = 0 \text{ V, } I_{S} = 11 \text{ A,}$		390		ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI <sub>F</sub> / dt = 100 A/μs (Note 4)		5.7		μΟ

- Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature 2.  $I_{AS} = 5.5A$ ,  $V_{DD} = 50V$ ,  $R_{G} = 25 \Omega$ , Starting  $T_{J} = 25^{\circ}C$  3.  $I_{SD} \le 11A$ ,  $di/dt \le 200A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_{J} = 25^{\circ}C$  4. Pulse Test: Pulse width  $\le 300\mu s$ , Duty cycle  $\le 2\%$  5. Essentially independent of operating temperature





# Typical Characteristics (Continued)

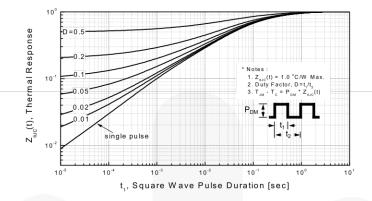


Figure 11-1. Transient Thermal Response Curve for FCP11N60

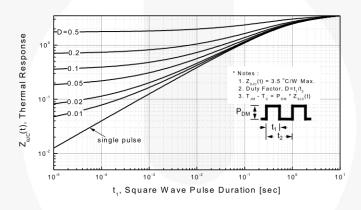
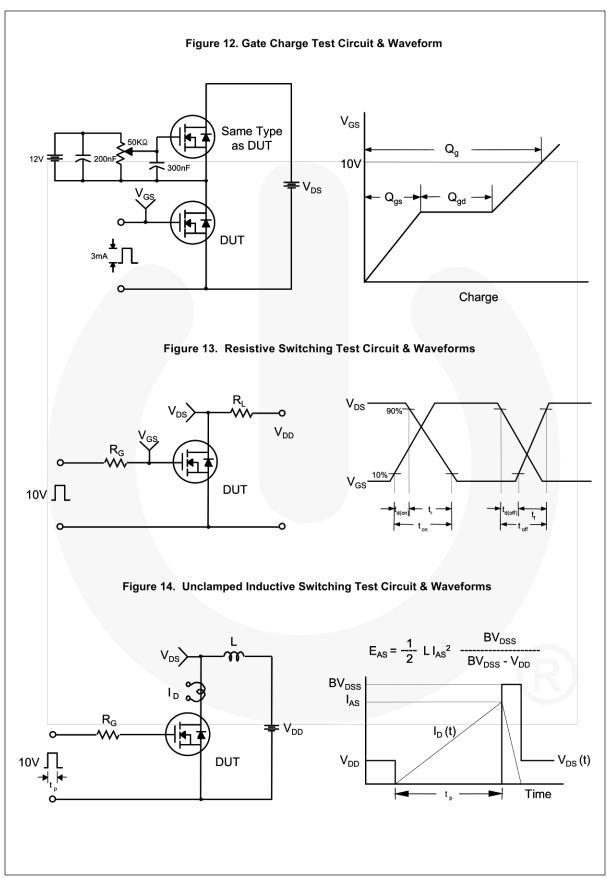
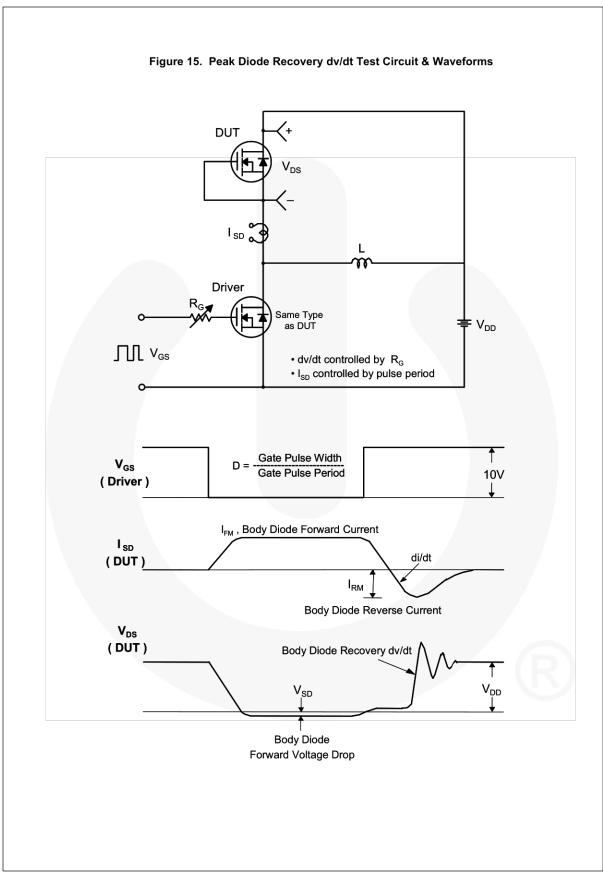


Figure 11-2. Transient Thermal Response Curve for FCPF11N60





## **Mechanical Dimensions**

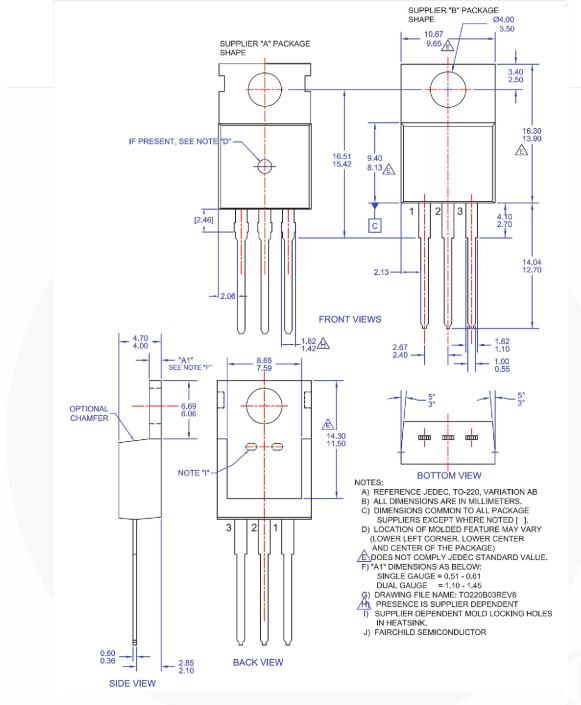


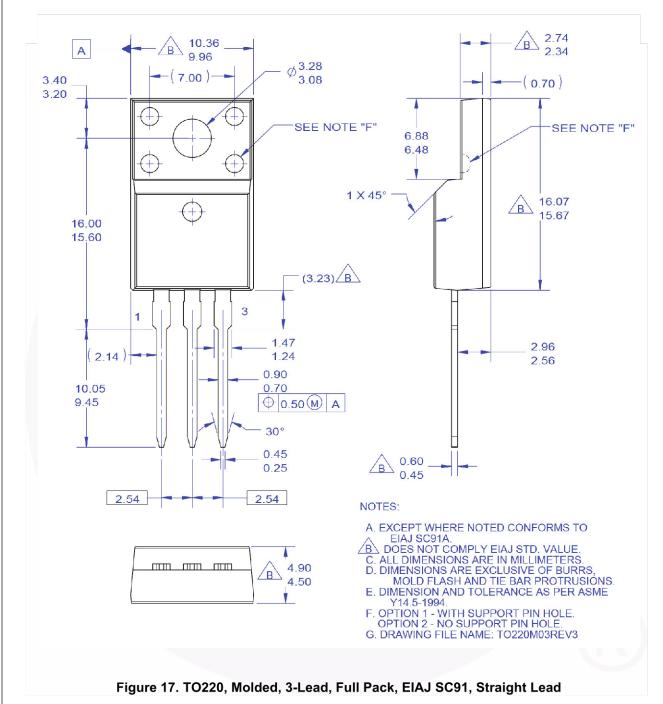
Figure 16. TO220, Molded, 3-Lead, Non Jedec Variation AB

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